L Number	Hits	Search Text	DB	Time stamp
1	2	("6674667").PN.	USPAT; US-PGPUB;	2004/07/26 07:46
4	13763	metal adj oxide adj semiconductor adj field adj effect adj transistor	-EPO;-JPO;- DERWENT USPAT; US-PGPUB; EPO; JPO;	2004/07/26 07:47
5	3	apply\$6 adj2 third adj voltage near1 potential adj3 gate	DERWENT USPAT; US-PGPUB; EPO; JPO;	2004/07/26 07:47
9	6	(apply\$6 adj2 first adj voltage near1 potential adj3 source) or (apply\$6 adj2 second adj voltage near1 potential adj3 drain) and gate adj1 oxide	DERWENT USPAT; US-PGPUB; EPO; JPO;	2004/07/26 07:47
10	5	((apply\$6 adj2 first adj voltage near1 potential adj3 source) or (apply\$6 adj2 second adj voltage near1 potential adj3 drain) and gate adj1 oxide) and conduction adj1 channel	DERWENT USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/07/26 07:47
11	2	(((apply\$6 adj2 first adj voltage near1 potential adj3 source) or (apply\$6 adj2 second adj voltage near1 potential adj3 drain) and gate adj1 oxide) and conduction adj1 channel) and	USPAT; US-PGPUB; EPO; JPO;	2004/07/26 07:47
12	2	negative adj gate adj1 potential near3 conduction adj1 channel (((apply\$6 adj2 first adj voltage near1 potential adj3 source) or (apply\$6 adj2 second adj voltage near1 potential adj3 drain) and gate adj1 oxide) and conduction adj1 channel) and negative adj gate adj1 potential	DERWENT USPAT; US-PGPUB; EPO; JPO;	2004/07/26 07:47
13	0	apply\$6 adj2 negative adj3 voltage near1 potential adj3 gate near5 MOSFEt	DERWENT USPAT; US-PGPUB; EPO; JPO;	2004/07/26 07:47
16	862	apply\$6 adj2 negative adj3 voltage adj3 gate	DERWENT USPAT; US-PGPUB; EPO; JPO;	2004/07/26 07:47
17	5020	apply\$6 adj2 negative adj (CAS ADJ latency ADJ control ADJ circuit) bias adj3 voltage adj3 gate	DERWENT USPAT; US-PGPUB; EPO; JPO;	2004/07/26 07:47
18	5020	apply\$6 adj1 negative adj (CAS ADJ latency ADJ control ADJ circuit) bias adj3 voltage adj3 gate	DERWENT USPAT; US-PGPUB; EPO; JPO;	2004/07/26 07:47
19	1107	(apply\$6 adj1 negative adj (CAS ADJ latency ADJ control ADJ circuit) bias adj3 voltage adj3 gate) and MOSFET	DERWENT USPAT; US-PGPUB; EPO; JPO;	2004/07/26 07:47
20	269	apply\$6 adj1 negative adj (CAS ADJ latency ADJ control ADJ circuit) bias adj3 voltage adj3 gate near5 mosfet	DERWENT USPAT; US-PGPUB; EPO; JPO;	2004/07/26 07:47
21	108	apply\$6 adj1 negative adj (CAS ADJ latency ADJ control ADJ circuit) bias adj3 voltage adj3 gate near5 mosfet	DERWENT US-PGPUB; EPO; JPO;	2004/07/26 07:47
2	3	"20020110033" or (("6674667").PN.)	DERWENT USPAT; US-PGPUB; EPO; JPO;	2004/07/26 07:48
3	2	"20020110033"	DERWENT USPAT; US-PGPUB; EPO; JPO;	2004/07/26 07:48
6	3	apply\$6 adj2 third adj3 voltage near1 potential adj3 gate	DERWENT USPAT; US-PGPUB; EPO; JPO;	2004/07/26 07:48

	7	6	apply\$6 adj2 first adj voltage near1 potential adj3 source	USPAT; US-PGPUB; EPO; JPO;	2004/07/26 07:48	
				DERWENT		
	8	7	apply\$6 adj2 second adj voltage near1 potential adj3 drain	USPAT;	2004/07/26 07:48	
	•	•	apply to day 2 5050114 day voltage from 1 potential days drain	US-PGPUB;	200 1101120 01110	
				EPO; JPO;		
				DERWENT		
	14	6	apply\$6 adj2 negative adj3 voltage near1 potential adj3 gate	USPAT;	2004/07/26 07:48	_
				US-PGPUB;		
				EPO; JPO;		
			(111.001.001.001.001.001.001.001.001.001	DERWENT		
	15	18	(("4,051,354") or ("5,324,681") or ("5,327,380") or	USPAT;	2004/07/26 07:48	
			("5,493,141") or ("5,764,096") or ("5,768,192") or ("5,781,477")	US-PGPUB;		
			or ("6,038,168") or ("6,229,733")).PN.	EPO; JPO; DERWENT		
	22	161	apply\$6 adj1 negative adj (CAS ADJ latency ADJ control ADJ	USPAT	2004/07/26 07:48	
	22	101	circuit) bias adj3 voltage adj3 gate near5 mosfet	USFAI	2004/01/20 01.40	
	23	153	apply\$6 adj1 negative adj (CAS ADJ latency ADJ control ADJ	USPAT	2004/07/26 07:48	
	20		circuit) bias adj1 voltage adj3 gate near5 mosfet	00.7	200	
	24	153	apply adj1 negative adj (CAS ADJ latency ADJ control ADJ	USPAT	2004/07/26_07:48	
			circuit) bias adj1 voltage adj3 gate near5 mosfet			
	25	153	appl\$ adj1 negative adj (CAS ADJ latency ADJ control ADJ	USPAT	2004/07/26 07:48	
			circuit) bias adj1 voltage adj3 gate near5 mosfet			
	26	31	(appl\$ adj1 negative adj (CAS ADJ latency ADJ control ADJ	USPAT	2004/07/26 07:48	
			circuit) bias adj1 voltage adj3 gate near5 mosfet) and negative			
	07	7	adj1 voltage ONO adj anti adj1 fuse	LICDAT	2004/07/26 07:40	
	27	· · ·	ONO adjanti adji i use	USPAT; US-PGPUB;	2004/07/26 07:48	
				EPO; JPO;		
				DERWENT		
	28	2	"20030235077"	USPAT;	2004/07/26 07:48	
				US-PGPUB;		
				EPO; JPO;		
				DERWENT		
	29	2	"20030235085"	USPAT;	2004/07/26 07:48	
				US-PGPUB;		
*		(*	· · · · · · · · · · · · · · · · · · ·	EPO; JPO; DERWENT	•	
	30	2	("5324681").PN.	USPAT;	2004/07/26 07:48	
		_	(352 733 1 7.1 14.	US-PGPUB;	250 1101125 01:10	
				EPO; JPO;		
				DERWENT		
	31	2	("5764096").PN.	USPAT;	2004/07/26 07:48	
				US-PGPUB;		
				EPO; JPO;		
	20	20		DERWENT	2004/07/26 07:40	
	32	29	metal adj oxide adj semiconductor adj field adj effect adj transistor near3 switch\$6 adj element	USPAT; US-PGPUB;	2004/07/26 07:48	
			transistor freato switchipo adj element	EPO; JPO;	,	
				DERWENT		
	33	37	(("3,992,701") or ("4,761,768") or ("4,766,569") or	USPAT;	2004/07/26 07:52	
			("5,172,204") or ("5,414,658") or ("5,544,118") or ("5,763,912")	US-PGPUB;		
			or ("5,828,099") or ("5,851,893") or ("5,867,425") or	EPO; JPO;		
			("5,978,273") or ("6,180,957") or ("6,243,298") or ("6,272,042")	DERWENT		
			or ("6,452,835") or ("6,456,535") or ("6,504,762") or			
	34	40	("6,510,086") or ("6,664,601")).PN.	LICDAT	2004/07/26 07:54	
	34	19	(("3,992,701") or ("4,761,768") or ("4,766,569") or ("5,172,204") or ("5,414,658") or ("5,544,118") or ("5,763,912")	USPAT	2004/07/26 07:54	
			or ("5,828,099") or ("5,851,893") or ("5,867,425") or			
			("5,978,273") or ("6,180,957") or ("6,243,298") or ("6,272,042")			
		,	or ("6,452,835") or ("6,456,535") or ("6,504,762") or			
			("6,510,086") or ("6,664,601")).PN.			
	35	1	("6700821").PN.	USPAT	2004/07/26 07:54	

	37	2	("6521958").PN.	USPAT;	2004/07/26 07:55	
				US-PGPUB;		
			•	EPO; JPO;		
				DERWENT;		
				IBM_TDB		
	38	2	("20040114433").PN.	USPAT;	2004/07/26 07:55	
				US-PGPUB;		
				EPO; JPO;		
				DERWENT;		
				IBM_TDB		
	36	3	("6700821").PN.	USPAT;	2004/07/26 07:57	
			US-PGPUB:			
				EPO; JPO;	·	
				DERWENT;		
				IBM TDB		